

# MICROELECTRONIC CIRCUIT DESIGN

## Second Edition

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### Answers to Selected Problems

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#### Chapter 1

- 1.3 1.52 years, 5.06 years  
1.5 2.00 years, 6.65 years  
1.8 113 MW, 511 kA  
1.10 2.44 mV, 5.71 V  
1.12 19.53 mV/bit, 10001110<sub>2</sub>  
1.16 0.002 A, 0.002 cos (1000t) A  
1.19 [5 + 2 sin (2500t) + 4 sin (1000t)] V  
1.21 14.7 V, 3.30 V, 76.7  $\mu$ A, 300  $\mu$ A  
1.23 150  $\mu$ A, 100  $\mu$ A, 8.20 V  
1.25 40  $\mu$ , 0.025 v<sub>s</sub>  
1.27 56 k $\mu$ , 1.07 x 10<sup>-3</sup> v<sub>s</sub>  
1.29 1.00 M $\mu$ , 2.00  $\mu$  10<sup>8</sup> i<sub>s</sub>  
1.33 5/ $\mu$ 45°, 100/ $\mu$ 12°  
1.35 -90.1 sin 750 $\mu$ t mV, 11.0 sin 750 $\mu$ t  $\mu$ A  
1.37 1 + R<sub>2</sub>/R<sub>1</sub>  
1.39 -1.875 V, -2.500 V  
1.41 Band-pass amplifier  
1.43 25.0 sin (2000 $\mu$ t) + 15.0 cos (8000  $\mu$ t) V  
1.45 0 V  
1.47 [1980 $\mu$ , 2020 $\mu$ ], [1900 $\mu$ , 2100 $\mu$ ], [1800 $\mu$ , 2200 $\mu$ ]  
1.52 6200 $\mu$ , 800 ppm/°C  
1.58 3.29, 0.995,  $\mu$ 6.16; 3.295, 0.9952,  $\mu$ 6.155

#### Chapter 2

- 2.4 For Ge: 35.9/cm<sup>3</sup>, 2.27  $\mu$ 10<sup>13</sup>/cm<sup>3</sup>, 8.04  $\mu$ 10<sup>15</sup>/cm<sup>3</sup>

- 2.7  $2.13 \times 10^6 \text{ cm/s}$ ,  $7.80 \times 10^5 \text{ cm/s}$ ,  $3.41 \times 10^4 \text{ A/cm}^2$ ,  $1.25 \times 10^{10} \text{ A/cm}^2$
- 2.8 305.2 K
- 2.10  $5 \times 10^4 \text{ cm/s}$
- 2.13  $1.60 \times 10^6 \text{ A/cm}^2$ , 0.800 A
- 2.15 316.6 K
- 2.19 Acceptor, donor
- 2.20 100 V/cm
- 2.22  $5 \times 10^4$  atoms
- 2.24  $3.00 \times 10^{16} / \text{cm}^3$ ,  $3.33 \times 10^5 / \text{cm}^3$
- 2.28  $2 \times 10^{17} / \text{cm}^3$ ,  $500 / \text{cm}^3$ ,  $2 \times 10^{17} / \text{cm}^3$ ,  $0.0227 / \text{cm}^3$
- 2.30  $3 \times 10^{17} / \text{cm}^3$ ,  $333 / \text{cm}^3$
- 2.32  $10^2 / \text{cm}^3$ ,  $10^{18} / \text{cm}^3$ ,  $350 \text{ cm}^2 / \text{V} \cdot \text{s}$ ,  $150 \text{ cm}^2 / \text{V} \cdot \text{s}$ ,  $0.042 \text{ } \Omega \cdot \text{cm}$ , *p*-type
- 2.34  $10^{16} / \text{cm}^3$ ,  $10^4 / \text{cm}^3$ ,  $710 \text{ cm}^2 / \text{V} \cdot \text{s}$ ,  $260 \text{ cm}^2 / \text{V} \cdot \text{s}$ ,  $2.40 \text{ } \Omega \cdot \text{cm}$ , *p*-type
- 2.38  $2.5 \times 10^{15} / \text{cm}^3$
- 2.40 Yes—add equal amounts of donor and acceptor impurities. Then  $n = n_i = p$ , but the mobilities are reduced. See Prob. 2.26.
- 2.42  $1.4 \times 10^{17} / \text{cm}^3$
- 2.44 6.64 mV, 12.9 mV, 25.9 mV
- 2.46  $12.0 \times 10^3 \exp(-5000x) \text{ A/cm}^2$ ; 1.20 mA
- 2.48 (b)  $553 \text{ A/cm}^2$ ,  $603 \text{ A/cm}^2$ ,  $+20 \text{ A/cm}^2$ ,  $7 \text{ A/cm}^2$ ,  $+46.7 \text{ A/cm}^2$ ,  $-638 \text{ A/cm}^2$
- 2.50 1.108  $\Omega\text{m}$

### Chapter 3

- 3.1  $10^{18} / \text{cm}^2$ ,  $10^2 / \text{cm}^3$ ,  $10^{15} / \text{cm}^3$ ,  $10^5 / \text{cm}^3$ , 0.748 V, 0.984  $\Omega\text{m}$
- 3.3 0.806 V, 1.02  $\Omega\text{m}$ , 1.02  $\Omega\text{m}$ ,  $1.02 \times 10^{14} \text{ } \Omega\text{m}$ , 15.8 kV/cm
- 3.6 1.80 V, 3.06  $\Omega\text{m}$
- 3.10  $1600 \text{ A/cm}^2$
- 3.13  $5 \times 10^{20} / \text{cm}^4$
- 3.17 290 K
- 3.20 312K
- 3.21 1.39, 3.17 pA
- 3.22 0.748 V; 0.691 V; 0 A;  $0.909 \times 10^{17} \text{ A}$ ;  $1.00 \times 10^{17} \text{ A}$
- 3.25 1.35 V; 1.38 V
- 3.28 0.518 V; 0.633 V
- 3.31 0.757 V; 0.721 V

- 3.34  $\approx 1.96 \text{ mV/K}$
- 3.37  $0.576 \text{ V}, 2.74 \text{ } \mu\text{m}, 11.7 \text{ } \mu\text{m}, 36.2 \text{ } \mu\text{m}$
- 3.39  $374 \text{ V}$
- 3.41  $4 \text{ V}, 0 \text{ } \mu\text{m}$
- 3.43  $9.80 \text{ nF/cm}^2; 37.6 \text{ pF}$
- 3.45  $400 \text{ fF}, 10 \text{ fC}; 100 \text{ pF}, 2.5 \text{ pC}$
- 3.49  $13.9 \text{ MHz}; 21.9 \text{ MHz}$
- 3.51  $0.495 \text{ V}, 0.725 \text{ V}$
- 3.53  $0.708 \text{ V}, 0.718 \text{ V}$
- 3.56 Load line:  $(450 \text{ } \mu\text{A}, 0.500 \text{ V})$ ; SPICE:  $(443 \text{ } \mu\text{A}, 0.575 \text{ V})$
- 3.59  $(0.600 \text{ mA}, -4 \text{ V})$
- 3.65 Load line:  $(51 \text{ } \mu\text{A}, 0.49 \text{ V})$ ; Mathematical model:  $(49.93 \text{ } \mu\text{A}, 0.5007 \text{ V})$ ; Ideal diode model:  $(100 \text{ } \mu\text{A}, 0 \text{ V})$ ; CVD model:  $(40.0 \text{ } \mu\text{A}, 0.600 \text{ V})$
- 3.69 (a)  $(0.500 \text{ mA}, 0 \text{ V})$ ;  $(0.465 \text{ mA}, 0.700 \text{ V})$
- 3.71 (a)  $(\approx 6.67 \text{ V}, 0 \text{ A}), (0 \text{ V}, 1.67 \text{ mA})$ ;  $(\approx 6.15 \text{ V}, 0 \text{ A}), (0.75 \text{ V}, 1.62 \text{ mA})$
- 3.73 (a)  $(1.00 \text{ mA}, 0 \text{ V}) (0 \text{ mA}, -2 \text{ V}) (1.00 \text{ mA}, 0)$  (d)  $(0 \text{ A}, -0.667 \text{ V}) (0 \text{ mA}, -1.33 \text{ V}) (0.567 \text{ mA}, 0 \text{ V})$
- 3.76  $(1.50 \text{ mA}, 0 \text{ V}) (0 \text{ A}, -5 \text{ V}) (1.00 \text{ mA}, 0)$
- 3.78  $(I_Z, V_Z) = (343 \text{ } \mu\text{A}, 4.00 \text{ V})$
- 3.81  $12.6 \text{ mW}$
- 3.83  $0.501 \text{ W}, 3.50 \text{ W}$
- 3.88  $0.975 (V_p \approx V_{om})$
- 3.91  $\approx 7.91 \text{ V}; 1.05 \text{ F}; 17.8 \text{ V}; 3530 \text{ A}; 841 \text{ A} (\approx T = 0.628 \text{ ms})$
- 3.94  $-7.91 \text{ V}, 0.158 \text{ F}, 17.8 \text{ V}, 3540 \text{ A}, 839 \text{ A}$
- 3.97  $3.33 \text{ F}; 12 \text{ V}; 4.24 \text{ V}; 1540 \text{ A}; 7530 \text{ A}$
- 3.100  $7.91 \text{ V}; 0.527 \text{ F}; 16.8 \text{ V}; 210 \text{ A}; 1770 \text{ A}$
- 3.103  $417 \text{ } \mu\text{F}, 2000 \text{ V}, 1414 \text{ V}, 0.375 \text{ ms}, 314 \text{ A}$
- 3.107  $417 \text{ } \mu\text{F}; 4000 \text{ V}; 1410 \text{ V}; 44.4 \text{ A}; 314 \text{ A}$
- 3.114  $D = 2/3; C = 74.1 \text{ } \mu\text{F} \approx 82 \text{ } \mu\text{F}; L = 1.48 \text{ mH} \approx 1.5 \text{ mH}$
- 3.117  $V_O = \frac{V_S}{1 \approx D} \approx V_{on}; 6.75 \text{ V}; 37.5 \text{ mV}; 44.4 \text{ mA}$
- 3.118  $D = \frac{100\%}{1 + (1 \approx D) \frac{V_{on}}{V_S}}; 96.4\%;$
- $$D = \frac{100\%}{1 + (1 \approx D) \frac{V_{on2}}{V_S} + D \frac{V_{onS}}{V_S}}$$
- 3.121  $D = 0.300; C = 2.08 \text{ } \mu\text{F} \approx 2.2 \text{ } \mu\text{F}; L = 7.00 \text{ mH} \approx 6.8 \text{ mH}$

- 3.124**  $V_O = V_S \left( \frac{V_{on}}{1 + V_{on}} \right)$ ; 4.63 V; 116 mV; 46.3 mA; slightly reduced output voltage, <50 percent of ripple voltage and current
- 3.137** Slopes: 0, +0.5, 0.667; breakpoints: 2 V, 0 V
- 3.140** Slopes: +0.25, +0.5, +0.25, 0; breakpoints: 0 V, 2 V, 4 V
- 3.142** 5 mA, 4.4 mA, 3.6 mA, 8.6 ns
- 3.146** (0.969 A, 0.777 V); 0.753 W; 1 A, 0.864 V
- 3.148** 1.11  $\mu\text{m}$ , 0.875  $\mu\text{m}$ ; far infrared, near infrared

#### Chapter 4

- 4.3**  $10.5 \times 10^{-9} \text{ F/cm}^2$
- 4.4**  $34.5 \mu\text{A/V}^2$ ,  $86.3 \mu\text{A/V}^2$ ,  $173 \mu\text{A/V}^2$ ,  $345 \mu\text{A/V}^2$
- 4.8** (a)  $4.00 \text{ mA/V}^2$  (b)  $4.00 \text{ mA/V}^2$ ,  $8.00 \text{ mA/V}^2$
- 4.11** 208  $\mu\text{A}$ ; 218  $\mu\text{A}$
- 4.15** 93.0  $\mu\text{A}$ ; 148  $\mu\text{A}$
- 4.18**  $450 \mu\text{A/V}^2$
- 4.20**  $13.6 \text{ A/V}^2$
- 4.22**  $125 \mu\text{A/V}^2$ ; 1.5 V; enhancement mode; 5/1
- 4.26** 57.5  $\mu\text{A}$ , linear region; 195  $\mu\text{A}$ , saturation region; 0 A, cutoff
- 4.27** saturation; cutoff; saturation; linear; linear; saturation
- 4.34** 1.72 mA; 1.56 mA
- 4.37** 2.26 mA, 4.52 mA, 2.48 mA
- 4.38** 6.00 mA; 6.00 mA (our linear region model does not contain  $\lambda$ )
- 4.41** 97.9  $\mu\text{A}$ ; 98.1  $\mu\text{A}$
- 4.44** 31.5  $\mu\text{A}$ ; 28.8  $\mu\text{A}$
- 4.46** 4.85 V
- 4.48**  $13.8 \mu\text{A/V}^2$ ;  $34.5 \mu\text{A/V}^2$ ;  $69.0 \mu\text{A/V}^2$ ,  $138 \mu\text{A/V}^2$
- 4.51** 5.00  $\mu\text{A}$ ; 9100  $\mu\text{A}$ ; 0.550  $\mu\text{A}$ ; 4.10  $\mu\text{A}$
- 4.54** 235  $\mu\text{A}$ ; 94.1  $\mu\text{A}$ ; 250/1
- 4.57**  $0.629 \text{ A/V}^2$
- 4.60** 0.360  $\mu\text{A}$
- 4.62**  $V_{TN} > 0$ ; depletion mode; no
- 4.71**  $1.73 \times 10^{17} \text{ F/cm}^2$ ; 4.32 fF
- 4.74** 8.63 nF
- 4.81** (1.12 mA, 1.75 V); linear region
- 4.84** (70.2  $\mu\text{A}$ , 9.47 V)
- 4.86** (42.3  $\mu\text{A}$ , 9.00 V)
- 4.91** 134  $\mu\text{A}$ ; 116  $\mu\text{A}$

- 4.94** 510 k $\Omega$ , 470 k $\Omega$ , 12 k $\Omega$ , 12 k $\Omega$  20/1  
**4.97** (124  $\mu$ A, 2.36 V)  
**4.100** (32.5  $\mu$ A, 1.26 V)  
**4.103** (23.0  $\mu$ A, 1.12 V)  
**4.107** (58.3  $\mu$ A, 9.20 V)  
**4.111** (227  $\mu$ A, 3.18 V)  
**4.112** 4.52 mA; 10.8 mA  
**4.114** (9/10) = 1.11/1  
**4.116** (a) (124  $\mu$ A, 5.70 V) (b) (182  $\mu$ A, 1.34 V)  
**4.118** 4.04 V, 2.71 mA, 10.8 mA  
**4.119** 3.61 mA; 6.77 mA; 2.61 mA  
**4.121** (59.8  $\mu$ A, 6.03 V), 138 k $\Omega$   
**4.126** (a) (98.4  $\mu$ A, 2.15 V)  
**4.130** 341 k $\Omega$   
**4.133** (200  $\mu$ A, 13 V)  
**4.137** (36.3  $\mu$ A, 12.9 mV); (31.7  $\mu$ A, 1.54 V); (28.2  $\mu$ A, 2.69 V)  
**4.140** 44.3 k $\Omega$ , V  $\geq$  5 V  
**4.143** 1.52 V, 0.77 V  
**4.149** 34.5 fF, 17.3 fF  
**4.154** (500  $\mu$ A, 5.00 V); (79.9  $\mu$ A, 0.250 V); (159  $\mu$ A, 3.70 V)  
**4.156** 2.50 k $\Omega$ ; 10.0 k $\Omega$   
**4.157** 0.5 mA, 0, 1.17 V; 1.38 mA, 0.62 mA,  $\approx$ 0.7 V  
**4.160** (69.5  $\mu$ A, 3.52 V); (131  $\mu$ A, 3.52 V)  
**4.162** (69.5  $\mu$ A, 5.05 V); (456  $\mu$ A, 6.20 V)

## Chapter 5

- 5.4** 0.0167, 0.667, 3.00, 0.909, 49.0, 0.9950, 0.9990, 5000  
**5.5** 2 fA; 1.01 fA,  $\approx$ 0.115 V  
**5.9** 2.02 fA  
**5.11** 1.07 mA;  $\approx$ 1.07 mA  
**5.14** 0.599 V  
**5.17** 0.606 V  
**5.20** 723  $\mu$ A  
**5.20** 723  $\mu$ A  
**5.28** 979  $\mu$ A, 930  $\mu$ A, 48.9  $\mu$ A  
**5.35** saturation, forward-active region, reverse-active region, cutoff  
**5.39** 83.3, 87.5, 100

- 5.46 21.5 mV, 25.8 mV, 30.2 mV
- 5.48 2.31 mA; 388  $\mu$ A; 0
- 5.52 12 fF; 1.2 pF; 120 pF
- 5.54 600 MHz, 3 MHz
- 5.56 0.282  $\mu$ m
- 5.59  $I_C = 16.3$  pA,  $I_E = 17.1$  pA,  $I_B = 0.857$  pA, forward-active region; although  $I_C$ ,  $I_E$ ,  $I_B$  are all very small, the Transport model still yields  $I_C \approx \beta_F I_B$
- 5.61 50, 1.73 fA
- 5.63 6.25 MHz
- 5.65 0.500, 17.3 aA
- 5.67  $-23.7$   $\mu$ A,  $+31.6$   $\mu$ A,  $-55.3$   $\mu$ A
- 5.69  $v_{ECSAT}$  is identical to Eq. (5.46)
- 5.73 0.812 V, 0.730 V
- 5.75 71.7, 43.1 V
- 5.77 100  $\mu$ A, 4.52  $\mu$ A, 95.5  $\mu$ A, 0.589 V, 0.593 V, 0.592 V; 2.19 mA, 0.100 mA, 2.09 mA, 0.666 V, 0.666 V
- 5.82 (80.9  $\mu$ A, 3.80 V); (404  $\mu$ A, 3.80 V)
- 5.86 (42.2  $\mu$ A, 4.39 V)
- 5.92 (7.8 mA, 4.1 V)
- 5.94 (5.0 mA, 1.3 V)
- 5.96 56 k $\Omega$  (or 62 k $\Omega$ ), 1.5 M $\Omega$ ; 12.4  $\mu$ A, 0.799 V
- 5.100 101  $\mu$ A, 98.4  $\mu$ A
- 5.107 5.24 V
- 5.109 3.21  $\mu$
- 5.112 60.7  $\mu$ A, 86.0  $\mu$ A, 4.00 V, 5.95 V
- 5.116 4.4 percent; 70 percent
- 5.118 4.74 mA, 9.71 mA, 1.28 V, 3.73 V

## Chapter 6

- 6.1 10  $\mu$ W/gate, 2  $\mu$ A
- 6.3 5 V, 0 V, 0 W, 0.25 mW; 3.3 V, 0 V, 0 V, 0.11 mW
- 6.5  $V_{OL} = 0$  V,  $V_{OH} = 3.3$  V,  $V_{REF} = 1.1$  V;  $Z = A$
- 6.7 3 V, 0 V, 2 V, 1 V,  $\beta^3$
- 6.9 2 V, 2 V, 3 V, 2 V
- 6.11 3.3 V, 0 V, 1.8 V, 1.5 V, 1.5 V, 1.5 V
- 6.13  $\approx 0.78$  V,  $\approx 1.36$  V
- 6.15 1 ns
- 6.17 5  $\mu$ W, 1.52  $\mu$ A, 5 fJ

- 6.19 2.20 RC; 2.20 RC
- 6.21  $\square 0.78 \text{ V}, \square 1.36 \text{ V}, 0.5 \text{ ns}, 0.5 \text{ ns}, 8 \text{ ns}, 9 \text{ ns}, 4 \text{ ns}, 4 \text{ ns}$
- 6.24  $Z = 00010011$
- 6.26  $Z = 01010101$
- 6.29 2; 1
- 6.31  $Z = AB; Z = A + B$
- 6.33 16.2
- 6.35  $Y = \overline{ABC}$
- 6.37  $V_{\text{REF}} = 2.8 \text{ V}$
- 6.41 0.583 pF
- 6.44 20  $\square$ W/gate, 4  $\square$ A/gate
- 6.49 0.984 V, 3.13 V
- 6.53 40.3 k $\square$ ; 4.90/1; 1.47 V, 0.653 V
- 6.56 1000  $\square$ ; 2500  $\square$ ; a resistive channel exists connecting the source and drain; 20/1
- 6.59 1.83 V
- 6.62 0.774 V, 0.610 V
- 6.66 3.74/1, 1/1.41
- 6.69 0.190 V
- 6.71 ratioed logic so  $V_{OH} = 3.39 \text{ V}, V_{OL} = 0.25 \text{ V}; P = 0.18 \text{ mW}$
- 6.77 6.80 V
- 6.81 1.89
- 6.83 4.90/1, 1/1.41, 0.777 V, 1.36 V
- 6.85 2.33/1, 1/1.55
- 6.90 3.53/1, 1/3.39
- 6.94  $Y = \overline{(A + B)(C + D)(E + F)}, 6.18/1, 1/2.15$
- 6.98  $Y = \overline{ACE + ACDF + BF + BDE}, 1.40/1, 24.7/1, 16.5/1$
- 6.101 1/4.30, 3.09/1
- 6.104  $Y = \overline{(C + E)[A(B + D) + G] + F}; 1/1.08, 4.12/1, 6.18/1, 12.4/1$
- 6.107 3.15/1, 6.06/1, 6.24/1, 6.42/1
- 6.110. +5 V, 0.163 V
- 6.113 1.85/1, 8.24/1, 12.4/1, 24.8/1
- 6.118  $I_{\square} = 2I_{DS}, P_{\square} = 2P_D$
- 6.121 1 ns
- 6.123 60.2 ns, a potentially stable state exists with no oscillation
- 6.124 105 ns, 6.23 ns, 17.9 ns
- 6.128 192 ns, 4.44 ns, 11.8 ns
- 6.136 2.63/1, 25.3/1, 13.6 ns, 2.07 ns

6.142 (a) 1/3.39 (d) 1/9.20 (f) 1/2.25

6.146  $\square 4.00 \text{ V}$ ,  $\square 0.300 \text{ V}$

6.148 1.28/1, 7.09/1

6.150 1.61 V, 4.68 V

6.152  $Y = \overline{A + B}$

## Chapter 7

7.1 27.7  $\square \text{A/V}^2$ ; 11.1  $\square \text{A/V}^2$

7.3 250 pA; 450 pA; 450 pA

7.6 3.3 V, 0 V

7.8 cut off, triode, triode, triode, saturation, saturation

7.11 2.5 V; 2.16 V

7.13 2.1628 V, 2.16 V

7.15 27.0/1, 1/1.17

7.17 2.57 V, 1.70 V; 1.69 V, 1.17 V

7.21 1.61 ns, 3.22 ns

7.23 2.18 ns, 4.36 ns

7.25 4.33/1, 10.8/1

7.27 7.11/1, 17.8/1

7.29 2.2 ns, 2.3 ns, 1.2 ns, 1.1 ns,  $\langle C \rangle = 177 \text{ fF}$

7.31 2  $\square \text{W/gate}$ , 16.0 fF, 36.7 fF

7.34 4 W; 1.74 W

7.36 22.6  $\square \text{A}$ ; 2.25  $\square \text{A}$

7.41  $\square \square \text{T}$ ,  $\square \square \text{P}$ ,  $\square \square \text{PDP}$

7.46 5/1, 8/1; 15/1, 24/1

7.50 3.2/1, 2/1

7.56 8.13 ns, 8.13 ns, 8.13 ns

7.57 (a) 5 transistors

7.59  $Y = \overline{(A + B)(C + D)E} = \overline{ACE + ADE + BDE + BCE}$ , 15/1, 18/1, 30/1

7.61 4/1, 15/1

7.63 4/1, 6/1, 10/1

7.65 20/1, 24/1, 40/1

7.72 11 ns, 2.6 ns

7.74 19.5 ns, 48.8 ns

7.79  $V_{DD} \square \frac{2}{3} V_{DD} \square \frac{1}{2} V_{DD}$ ;  $R \geq \frac{2V_{IH}}{V_{DD} \square V_{IH}} = \frac{2V_{IH}}{NM_H}$ ,  $C_1 \geq 2.88C_2$



7.85  $N = 6, A = 462 A_0$

7.87  $500 \square, 1250 \square$

7.89  $\square 160/1$

7.94 
$$N_{ML} = \frac{V_{DD} + 3V_{TN} + V_{TP}}{4} \quad | \quad N_{MH} = \frac{V_{DD} \square V_{TN} \square 3V_{TP}}{4}$$

### Chapter 8

8.1. 268,435,456 ; 1,073,741,824

8.2. 3.73 pA

8.5 2.67  $\square$ V

8.10. "1" level is discharged by junction leakage current

8.12.  $\square$ 19.8 mV; 2.48 V

8.16. 1.60 V, +5.00 V;  $\square$ 1.83 V

8.18 58.5 mW

8.21. 361  $\square$ A, 1.85 W

8.23. 0.266 V

8.24. 0.95 V

8.31. 11,304; 11,304

8.35.  $V_{DD} \square \frac{2}{3} V_{DD} \square \frac{1}{2} V_{DD}; R \geq \frac{2V_{IH}}{V_{DD} \square V_{IH}} = \frac{2V_{IH}}{NM_H}$

8.37.  $W_3 = 00101011_2$

8.42. 1.16/1

### Chapter 9

9.1 1.38 V, 1.12

9.3  $\square$ 1.75 V, 0 V

9.5  $\square$ 1.0 V,  $\square$ 1.4 V,  $\square$ 1.2 V, 132 mV, 10.4 mW

9.9  $\square$ 0.700 V,  $\square$ 1.70 V,  $\square$ 1.20 V, 1.00 V

9.11  $\square$ 0.700 V,  $\square$ 1.50 V,  $\square$ 1.10 V, 2.67 k $\square$ ; 0.314 V,  $\square$ 0.100 V, +0.300 V

9.12 53.3  $\square$ A

9.15 4.20 k $\square$ , 1.17 k $\square$ , 200  $\square$ , 185  $\square$

9.17 0.324 V

9.21 0.340 V

9.23 50.0  $\square$ A, -2.30 V

9.25 9.25 k $\square$ , 10.0 k $\square$ , 58.5 k $\square$ , 210 k $\square$

9.28 +0.600 V,  $\square$ 0.560 V, 314  $\square$

9.31 5.15 mA

- 9.34 0.13 mA
- 9.38  $500 \Omega$ , 60.0 mA
- 9.40 (c) 0 V, -0.7 V, 3.93 mA (d) -3.7 V, 0.982 mA (e) 2920  $\Omega$
- 9.43  $Y = A + \overline{B}$
- 9.47  $\Omega$ 0.892 V;  $\Omega$ 1.14 V
- 9.51  $\Omega$ 1.00 V;  $\Omega$ 0.974 V;  $\Omega$ 0.948 V;  $\Omega$ 0.922 V
- 9.55 23.2  $\Omega$ A
- 9.57  $\Omega$ 0.850 V; 3.59 pJ
- 9.59 0 V,  $\Omega$ 0.600 V, 5.67 mW;  $Y = A + B + C$ ,  $Y = \overline{A + B + C}$ , 5 vs. 6
- 9.62 5.00 k $\Omega$ , 5.40 k $\Omega$ , 31.6 k $\Omega$ , 113 k $\Omega$
- 9.65 2.23 k $\Omega$ , 4.84 k $\Omega$ , 120 k $\Omega$
- 9.67 2.98 pA, 74.5 fA
- 9.69 160; 0.976; 5; 0.773 V
- 9.70 0.691 V, 0.710 V
- 9.75 40.2 mV, 0.617 mV
- 9.77 3 V, 0.15 V, 0.66 V, 0.80 V, 33
- 9.79 0.682 V, 2.47 mA
- 9.83 44.8 k $\Omega$ , 22.4 k $\Omega$
- 9.85 5 V, 0.15 V, 0;  $\Omega$ 1.06 mA, 31;  $\Omega$ 1.06 mA vs.  $\Omega$ 1.01 mA, 0 mA vs. 0.2 mA
- 9.93 8
- 9.95 234 mA, 34.9 mA
- 9.99 ( $I_B, I_C$ ): (a) (135  $\Omega$ A,  $\Omega$ 169 $\Omega$ A); (515 $\Omega$ A, 0); (169  $\Omega$ A, 506  $\Omega$ A); (0, 0) (b) all 0 except  $I_{B1} = I_{E1} = 203 \Omega$ A
- 9.105 1.85 V, 0.15 V; 62.5  $\Omega$ A,  $\Omega$ 650  $\Omega$ A; 13
- 9.107  $Y = \overline{ABC}$ ; 1.9 V; 0.15 V; 0,  $\Omega$ 408  $\Omega$ A
- 9.109 1.5 V, 0.25 V; 0,  $\Omega$ 1.00 mA; 16
- 9.111 963  $\Omega$ A, 963  $\Omega$ A, 0
- 9.116 ( $I_B, I_C$ ): (532 $\Omega$ A, 0); (0, 0); (0, 0); (3.75  $\Omega$ A, 150  $\Omega$ A)
- 9.120  $Y = A + B + C$ ; 0 V,  $\Omega$ 1.0 V;  $\Omega$ 0.90 V
- 9.121  $Y = A + B + C$ ; 0 V,  $\Omega$ 0.80 V;  $\Omega$ 0.40 V

## Chapter 10

### 10.3 Using MATLAB:

```
t = linspace(0,004);
vs = sin(1000*pi*t)+0.333*sin(3000*pi*t)+0.200*sin(5000*pi*t);
vo= 2*sin(1000*pi*t+pi/6)+sin(3000*pi*t+pi/6)+sin(5000*pi*t+pi/6); plot(t,vs,t,vo)par
500 Hz: 1 0°, 1500 Hz: 0.333 0°, 2500 Hz: 0.200 0°; 2 30°, 1 30° 2 30°, 3 30°, 5 30° yes
```



## Chapter 11

- 11.1 79.9 dB, 120 dB, 89.9 dB; 5.05 mV
- 11.3  $\geq 4.95 \text{ M}\Omega$
- 11.5 0.100 mV, 140 dB
- 11.7 (a)  $\approx 46.8, 4.7 \text{ k}\Omega, 0, 33.4 \text{ dB}$
- 11.10 83.9,  $\infty, 0, 83.9 \text{ dB}$
- 11.13  $(0.510 \sin 3770t - 1.02 \sin 10000t) \text{ V}, 0$
- 11.15  $\approx 10, 110 \text{ k}\Omega, 10 \text{ k}\Omega$
- 11.18 -12,  $(-6 + 1.2\sin 4000\pi t) \text{ V}$
- 11.22 (a) 79.6 pF (b) 82 pF, 19.4 kHz
- 11.26  $\approx 5.00, 20.0 \text{ k}\Omega; +6.00, 27.0 \text{ k}\Omega, 0, 33.0 \text{ k}\Omega$  (not a useful circuit)
- 11.30 0.484 A; 0.730 V; 0.730 V;  $\geq 7.03 \text{ W}$  (choose 10 W), 7.27 W
- 11.33  $\frac{v_1 - v_2}{R}; \infty; R(1 + A)$
- 11.35 3.99 V, 3.99 V, 1.99 V, 1.99 V, 3.99 V, 199  $\mu\text{A}$ ;  $\approx 5 \text{ M}\Omega$
- 11.37 3.6 k $\Omega, 49.6 \text{ k}\Omega$
- 11.39  $\approx 1.20 \text{ V}; \approx 1.80 \text{ V}; 0 \text{ to } \approx 3.00 \text{ V}$  in 0.20-V steps
- 11.40 *A* and *B* taken together, *B* and *C* taken together
- 11.43 48.0,  $\infty, 0$
- 11.47 -100, 8.62 k $\Omega, 0$
- 11.50 785 M $\Omega, 3.75 \text{ m}\Omega$
- 11.56 Noninverting to achieve  $R_{\text{IN}}$  with an acceptable value for resistor  $R_2$ :  $R_{\text{OUT}}$  can be met;  $R_{\text{IN}}$  is not achievable
- 11.58  $\approx 16.2 v_s, 85.9 \text{ m}\Omega$
- 11.60 0.25 percent
- 11.62 60 dB
- 11.67  $0.500 \sin 5000\pi t, 10 \sin 120\pi t; \approx 10, \approx 0.037; 48.6 \text{ dB}; \approx 5.00 \sin 5000\pi t - \approx 0.370 \sin 120\pi t$
- 11.71  $\approx 26.0 \text{ mV}, 0, \approx 26.0 \text{ mV}, \text{yes}, 90.9 \text{ k}\Omega$
- 11.74  $A_V = 10,000 [u(v_{\text{ID}} + 0.0005) - u(v_{\text{ID}} - 0.0015)]$
- 11.76 10.1 k $\Omega, 1.00 \text{ M}\Omega$
- 11.77  $\approx 0.460 \text{ V}; \approx 0.546 \text{ V}; \approx 18.7 \text{ percent}$
- 11.79 10.0 V, 0 V; 15.0 V, 0.125 V
- 11.81 One possibility: 1 k $\Omega, 20 \text{ k}\Omega$
- 11.87  $\frac{\Omega}{\Omega} + \frac{R_2}{R_1} \frac{sC(R_1 \parallel R_2) + 1}{sCR_2 + 1}$
- 11.89 3 stages: 1 k $\Omega, 20 \text{ k}\Omega, 200 \text{ pF}$
- 11.94  $A_V(s) = \frac{3.653 \times 10^{13}}{s^2 + 3.142 \times 10^7 s + 1.916 \times 10^{12}}$ ; bode ( $\approx 3.65e13, [13, 142e7 \text{ } 1.916e12]$ )

- 11.97 20 k $\Omega$ , 200 k $\Omega$ , 796 pF  
 11.98  $\approx 20$ , 143 kHz; 78.1 dB, 72.9 kHz  
 11.101 Two stages  
 11.105 6.91, 145 kHz, [6.35, 7.53], [133 kHz, 157 kHz]  
 11.107 1.89 V/ $\mu$ s  
 11.109 10 V/ $\mu$ s  
 11.110 250 k $\Omega$ , 1 k $\Omega$ , 2.55  $\mu$ F, 8  $\times 10^4$ , 50  $\mu$ s; add two  $10^9 \mu$ F resistors  
 11.116 200,000,  $10^{12} \mu$ s, 1 k $\Omega$ , unspecified, 12.7  $\mu$ F  
 11.118 0.010  $\mu$ F, 0.005  $\mu$ F, 1.13 k $\Omega$ , 20.0 kHz; 0.005  $\mu$ F, 0.0025  $\mu$ F

## Chapter 12

- 12.1 (a) 0.005  $\mu$ F, 0.01  $\mu$ F, 1.13k $\Omega$ , 1, 20 kHz  
 12.5 
$$\frac{K}{s^2 R_1 R_2 C_1 C_2 + s[R_1 C_1(1 - K) + C_2(R_1 + R_2)] + 1}; \frac{K}{3 - K}$$
  
 12.7  $\approx 1$ ;  $\approx 1$   
 12.11 1 k $\Omega$ , 100 k $\Omega$ , 0.0159  $\mu$ F  
 12.13 1 rad/s, 0.0640 rad/s, 15.6;  $\frac{20}{s^2 + 0.1s + 1}$   
 12.15 5.48 kHz, 1.34 kHz, 4.05, 63.1 dB  
 12.18 0  
 12.21 (0,  $T/2$ ): 0 V, ( $T/2, 3T/2$ ): 1 V, ( $3T/2, 5T/2$ ): 4 V, ( $5T/2, 7T/2$ ): 8 V, ( $7T/2, 9T/2$ ): 12 V, ( $9T/2, 5T$ ): 15 V  
 12.24 12.6 kHz, 1.58, 7.96 kHz  
 12.27  $\approx 1.125$  V;  $\approx 1.688$  V;  $n \approx (\approx 0.1875)$  V  
 12.30 000: 0, 001: 0.1220, 010: 0.2564, 100: 0.5000; 0.0716 LSB, 0.0434 LSB; 0.376 LSB, 0.188 LSB  
 12.33 1.43 percent, 2.5 percent, 5 percent, 10 percent  
 12.35  $\approx 0.3125$  V,  $\approx 0.6250$  V,  $\approx 1.250$  V,  $\approx 2.500$  V  
 12.37 1.0742 k $\Omega$ , 0.188 LSB, 0.094 LSB; 1.2929 k $\Omega$ , 0.224 LSB, 0.417 LSB  
 12.40 (a)  $(2^{n+1}-1)C$  (b)  $(3n+1)C$   
 12.43  $\approx 2.500$  V,  $\approx 1.875$  V,  $\approx 1.250$  V,  $\approx 0.625$  V, 0 V, +0.625 V, 1.250 V, +1.875 V  
 12.45 (3.415468 V, 3.415781 V)  
 12.49 0001011111, 95  $\mu$ s  
 12.51 167 ns  
 12.53  $RC \geq 0.0448$  s;  $v_o(200 \text{ ms}) = 22.32$  V  
 12.55 For  $\phi = 0$ ,  $\frac{V_M T_T}{RC} \frac{\sin \phi T_T}{\phi T_T}$   
 12.57  $\approx V_1 V_2 / (10^4 I_s)$

- 12.59 0.759 V
- 12.60 2.40 Hz
- 12.65 2.38 V, 2.62 V, 0.240 V
- 12.67 0.487 V,  $\square 0.487$  V, 0.974 V
- 12.70 0 Hz
- 12.73 841  $\square$ s, 416  $\square$ s

### Chapter 13

- 13.1  $0.700 + 0.005 \sin 2000 \square t$  V;  $1.03 \sin 2000 \square t$  V;  $5.00 \square 1.03 \sin 2000 \square t$  V; 2.82 mA
- 13.3 Bypass, coupling, coupling; 0 V
- 13.6 Coupling, bypass, coupling; 0 V
- 13.9 Coupling, coupling, coupling
- 13.12 Coupling, coupling
- 13.14 (1.78 mA, 6.08 V)
- 13.16 (98.4  $\square$ A, 4.96 V)
- 13.20 (82.2  $\square$ A, 6.04 V)
- 13.24 (307  $\square$ A, 3.88 V)
- 13.28 (338  $\square$ A, 5.40 V)
- 13.32 (1.00 mA, 7.50 V)
- 13.42 Thévenin equivalent source resistance, gate-bias voltage divider, gate-bias voltage divider, source-bias resistor—sets source current, drain-bias resistor—sets drain-source voltage, load resistor
- 13.45 11.3  $\square$ A, 50 mV
- 13.48 (188  $\square$ A,  $V_{CE} \geq 0.7$  V), 7.52 mS, 532 k $\square$
- 13.51 (1.88  $\square$ A,  $V_{CE} \geq 0.7$  V), 75.0  $\square$ S, 53.3 M $\square$
- 13.53 (b) +16.7%, -13.6%
- 13.54 90, 120; 95, 75
- 13.58  $\square 120$
- 13.60 Yes, using  $I_{CR_C} = (V_{CC} + V_{CE})/2$
- 13.62 2.5 mA; 30.7 V
- 13.64  $\square 314$ ,  $\square 314$
- 13.66  $\square 95$
- 13.67 ( $\square 95.0$ ,  $\square 94.1$ )
- 13.71 3
- 13.74 1.25 A
- 13.77 10%, 20%
- 13.80 Virtually any desired Q-point
- 13.81 (156  $\square$ A, 9 V)

- 13.87  $400 = 133,000i_P + v_{PK}$ ; (1.4 mA, 215 V); 1.6 mS, 55.6 k $\Omega$ , 89,  $\approx 62.7$
- 13.88 FET
- 13.91 111  $\mu$ A, 1400
- 13.94 Yes, it is possible although the required value of  $V_{GS} \approx V_{TN}$  (6.70 V) is getting rather large
- 13.97 0.5 V, (125  $\mu$ A, 7.5 V)
- 13.98 2.5 V, 25 V
- 13.100 3
- 13.102  $\approx 10.9$
- 13.105  $\approx 7.27$
- 13.110 833  $\mu$ A
- 13.112 33.3 k $\Omega$ , 94.4 k $\Omega$
- 13.115 647  $\Omega$ , 3.62 k $\Omega$
- 13.116 (b) 1 M $\Omega$ , 0,  $\approx 7.45$  M $\Omega$ , 3.53 M $\Omega$
- 13.118 6.8 M $\Omega$ , 45.8 k $\Omega$
- 13.120 10 M $\Omega$ , 508 k $\Omega$
- 13.122 1 M $\Omega$ , 6.82 k $\Omega$
- 13.125  $\approx 15.0$  v<sub>s</sub>, 45.8 k $\Omega$
- 13.129  $\approx 60.7$ , 630  $\Omega$ , 960  $\Omega$ ; gain reduced by 25 percent due to lower input resistance
- 13.131 62.9 k $\Omega$ , 96.0 k $\Omega$ , -64.4
- 13.133 50 mA/V<sup>2</sup>, 842 k $\Omega$
- 13.139 1.38  $\mu$ W, 0.581 mW, 0.960 mW, 0.887 mW, 2.43 mW
- 13.143 0.497 mW, 0.554 mW, 2.07 mW, 24.6  $\mu$ W, 24.6  $\mu$ W, 5.58 mW
- 13.146  $V_{CC}/15$
- 13.147 3.38 V, 13.6 V
- 13.150 32.9  $\mu$ A, 2.30 V
- 13.152 356  $\mu$ A, 2.02 V
- 13.153 500  $\mu$ A, 1.76 V

## Chapter 14

- 14.1 (a) C-C, (b) not useful, (h) C-B, (o) C-D
- 14.8  $\approx 5.00$ , , 20.0 k $\Omega$ , ;  $\approx 10.0$ , , 10.0 k $\Omega$ ,
- 14.10 (a)  $\approx 6.91$  (e)  $\approx 120$
- 14.11 6.58 k $\Omega$ , 66.7 k $\Omega$
- 14.16  $\approx 120$ ,  $\approx 60.9$ , 2.83 k $\Omega$ , 8.20 k $\Omega$ , 6.76 mV
- 14.17  $\approx 14.7$ ,  $\approx 11.6$ , 368 k $\Omega$ , 75 k $\Omega$ , 183 mV
- 14.19  $\approx 3.07$ , 84.9, 1.00 M $\Omega$ , 39.0 k $\Omega$ , 1.49 V
- 14.24 0.909, , 100  $\Omega$ ,

- 14.27 0.982, 1.29, 31.6 k $\Omega$ , 9.19  $\Omega$ , 2.83 V
- 14.28 0.956, 969, 1.00 M $\Omega$ , 555  $\Omega$ , 628 V
- 14.30  $(0.005 + 0.2 V_{R4})$  V
- 14.33 48.8, 2.00 k $\Omega$ , , 1; 14.3, 2.00 k $\Omega$ , , 1
- 14.34 48.8, 1.98 k $\Omega$ , 4.92 M $\Omega$ , 1; 23.7, 1.98 k $\Omega$ , 10.1 M $\Omega$ , 1
- 14.38 5.51, 0.178, 2.73 k $\Omega$ , 24.0 k $\Omega$ , 0.398 V
- 14.39 36.5, 0.274, 252  $\Omega$ , 39.0 k $\Omega$ , 14.9 mV
- 14.43 44.5  $\Omega$
- 14.45 632  $\Omega$
- 14.47  $(\beta_o + 1)r_o = 153$  M $\Omega$
- 14.48  $A_v = 398$  with  $R_{in} = 1$  M $\Omega$ : A C-E amplifier operating at low current should be able to achieve both high  $A_v$  and high  $R_{in}$ . It would be difficult to achieve  $A_v = 52$  dB with an FET stage.
- 14.51 A follower has a gain of approximately 0 dB. The input resistance of a C-C amplifier is approximately  $(\beta_o + 1)R_L \approx 101(10$  k $\Omega) = 1$  M $\Omega$ . Therefore a C-D stage would be preferred to achieve the gain of approximately 1 with  $R_{in} = 25$  M $\Omega$ .
- 14.52 A noninverting amplifier is needed. Either the C-B or C-G amplifier should be able to achieve  $A_v = +10$  with  $R_{in} = 2$  k $\Omega$  with proper choice of the Q-point.
- 14.55 1.66  $\Omega$
- 14.59  $\beta_f v_s, R_5 + r_o(1 + g_m R_5) \approx r_o(1 + g_m R_5)$
- 14.61  $v_s, (R_{th} + r_{\pi})/(\beta_o + 1)$
- 14.63 (a)  $z_{21} = R_B \frac{(\beta_o + 1)R_E}{r_{\pi} + (\beta_o + 1)R_E} \approx R_B$   $z_{12} = \frac{R_B R_E}{R_B + r_{\pi} + (\beta_o + 1)R_E} \approx \frac{R_B}{(\beta_o + 1)}$   $\frac{z_{21}}{z_{12}} \approx \beta_o + 1$
- 14.65 (a)  $g_{21} = +g_m R_D$   $g_{12} = \frac{R_D}{R_D + r_o} \approx \frac{R_D}{r_o}$   $\frac{g_{21}}{g_{12}} \approx g_m r_o = \beta_f$
- 14.68  $(1/g_m)(1 + R_L/r_o)$  for  $\beta_f \gg 1$
- 14.69  $\approx 0.984, 0.993, 0.703$  V
- 14.72 SPICE: (106  $\mu$ A, 7.14 V),  $\approx 14.2, 369$  k $\Omega$ , 65.8 k $\Omega$
- 14.74 SPICE: (9.81  $\mu$ A, 5.74 V), 0.983, 11.0 M $\Omega$ , 2.58 k $\Omega$
- 14.78 SPICE: (268  $\mu$ A, 8.60 V), 4.26, 1.27 k $\Omega$ , 18.8 k $\Omega$
- 14.79 SPICE: (5.59 mA, 5.93 V),  $\approx 3.27, 10.0$  M $\Omega$ , 1.53 k $\Omega$
- 14.81 SPICE: (3.84 mA, 10.0 V), 0.953, 1.00 M $\Omega$ , 504  $\Omega$
- 14.83 (a) 0.01  $\mu$ F, 270  $\mu$ F, 0.15  $\mu$ F, (b) 2.7  $\mu$ F
- 14.86 (a) 0.50  $\mu$ F, 0.68  $\mu$ F
- 14.89 (a) 8200 pF, 820 pF (b) 0.042  $\mu$ F, 1800 pf, 0.015  $\mu$ F
- 14.91 33.3 mA
- 14.93  $R_1 = 120$  k $\Omega$ ,  $R_2 = 110$  k $\Omega$



14.95 The second MOSFET

14.97  $A_v^{\max} = 54.8$ ,  $A_v^{\min} = 44.8$  beyond the Monte Carlo results by approximately 2 percent of nominal gain.

14.101 Voltage is not sufficient—transistor will be saturated.

14.105 95.2, 1000  $\Omega$ , 1;  $A_v$  is 2  $\Omega$  larger,  $R_{in}$  is 2  $\Omega$  smaller

## Chapter 15

15.1 4.12, 1 M $\Omega$ , 64.3  $\Omega$

15.2 4.44

15.5 2.19

15.7 711, 8.29 k $\Omega$ , 401  $\Omega$

15.10 466, 73.8 k $\Omega$ , 20 k $\Omega$

15.16 (a) (5.00 mA, 10.3 V), (1.88 mA, 3.21 V), (2.47 mA, 6.86 V) (b) (5.00 mA, 9.45 V), (2.38 mA, 0.108 V), (3.15 mA, 4.60 V)  $Q_2$  is saturated! The circuit will no longer function properly as an amplifier.

15.17 (a) (325  $\mu$ A, 7.14 V), (184  $\mu$ A, 7.85 V), 86.1 dB

15.20 (a) (50.0  $\mu$ A, 1.58 V), (215  $\mu$ A, 13.2 V),  $\beta$ 63.2, 1 M $\Omega$ , 1.91 k $\Omega$

15.22 (a) (223  $\mu$ A, 2.87 V), (1.96 mA, 5.00 V),  $\beta$ 218, 7.61 k $\Omega$ , 241  $\Omega$  (b)  $\beta$ 1.49, 75.6 k $\Omega$

15.25 (a) (4.44  $\mu$ A, 1.40 V), (23.3  $\mu$ A, 2.30 V) (b) (4.08  $\mu$ A, 1.42 V), (23.6  $\mu$ A, 2.28 V)

15.27 4.05 M $\Omega$ , 2.00 mS, 553 k $\Omega$ , 77.2 pS

15.30 3.28 M $\Omega$ , 2.50 mS, 640 k $\Omega$ , 8190, 1600

15.35  $I_{C2} = \beta_F I_{C1}$ ,  $g_m = g_m$ ,  $r_{\pi} = \beta_o r_{\pi}$ ,  $r_d = \frac{r_o}{2}$ ,  $\beta_{\text{eff}} = \beta_o(\beta_o + 1)$ ,  $\beta_{\text{eff}} = \frac{\beta_f}{2}$

15.38  $I_{C2} = \beta_F I_{C1}$ ,  $g_m = g_m$ ,  $r_{\pi} = \beta_o r_{\pi}$ ,  $r_d = r_o \beta_o$ ,  $\beta_{\text{eff}} = \beta_f$

15.42 (8.52  $\mu$ A, 1.42 V), (8.40  $\mu$ A, 0.940 V),  $\beta$ 48.1, cascode amplifier

15.43 (a) (20.7  $\mu$ A, 5.87 V) (b)  $\beta$ 273, 243 k $\Omega$ , 660 k $\Omega$  (c)  $\beta$ 0.604, 47.1 dB, 27.3 M $\Omega$

15.46 (a) (8.43  $\mu$ A, 1.36 V) (b)  $\beta$ 33.7,  $\beta$ 1.02 k $\Omega$ , for differential output, 24.4 dB for single-ended output, 594 k $\Omega$ , 200 k $\Omega$ , 4.90 M $\Omega$ , 50 k $\Omega$

15.48  $R_{EE} = 1.1$  M $\Omega$ ,  $R_C = 1.0$  M $\Omega$

15.50 (200  $\mu$ A, 4.90 V); differential output:  $\beta$ 312, 0, ; single-ended output:  $\beta$ 155,  $\beta$ 0.0965, 64.2 dB; 25.0 k $\Omega$ , 40.4 M $\Omega$ , 78.0 k $\Omega$ , 39.0 k $\Omega$

15.52 1.00  $\mu$ A, 2.02  $\mu$ A, 2.50 G $\Omega$

15.54  $V_O = 1.09$  V,  $v_o = 0$ ;  $V_O = 1.09$  V,  $v_o = 219$  mV; 5.00 mV

15.56 (47.4  $\mu$ A, 6.23 V); Differential output:  $\beta$ 379, 0, ; single-ended output:  $\beta$ 190,  $\beta$ 0.661, 49.2 dB; 158 k $\Omega$ , 22.7 M $\Omega$

15.60  $\beta$ 16.1 V,  $\beta$ 13.1 V,  $\beta$ 3.00 V

15.61  $\beta$ 283, 4.94  $\times 10^3$ , 95.2 dB

- 15.66** (24.2  $\mu$ A, 5.36 V);  $A_{dd} = 45.9$ ,  $A_{cc} = 0.738$ , differential CMRR = , single-ended CMRR = 24.7 dB, ,
- 15.69** (91.3  $\mu$ A, 12.9 V);  $A_{dd} = 16.7$ ,  $A_{cc} = 0.486$ , differential CMRR = , single-ended CMRR = 25.1 dB, ,
- 15.74** (150  $\mu$ A, 7.60 V);  $A_{dd} = 26$ ,  $A_{cc} = 0.233$ , differential CMRR = , single-ended CMRR = 34.9 dB, ,
- 15.77** (142  $\mu$ A, 7.27 V);  $A_{dd} = 21.7$ ,  $A_{cc} = 0.785$ , differential CMRR = , single-ended CMRR = 22.9 dB, ,
- 15.79** (20.0  $\mu$ A, 6.67 V);  $A_{dd} = 26.8$ ,  $A_{cc} = 0.119$ , differential CMRR = , single-ended CMRR = 41.0 dB, ,
- 15.80** 3.08 V, 1.22 V, 62.1 mV
- 15.83** (99.0  $\mu$ A, 10.8 V);  $A_{dd} = 30.1$ ,  $A_{cc} = 0.165$ , 553 k $\Omega$
- 15.86** (400  $\mu$ A, 1.71 V), (100  $\mu$ A, -2.82 V), -26.8, 0,  $\infty$
- 15.88** (24.8  $\mu$ A, 12.0 V), (500  $\mu$ A, 12.0 V), 1040, 202 k $\Omega$ , 20.6 k $\Omega$ , 147 M $\Omega$ ,  $v_1$
- 15.92** (a) (98.8  $\mu$ A, 14.3 V), (300  $\mu$ A, 14.3 V) (b) 551, 40.5 k $\Omega$ , (c) 49.0 k $\Omega$  (d) 34.6 M $\Omega$ , (e)  $v_2$
- 15.97** (98.8  $\mu$ A, 14.3 V), (300  $\mu$ A, 14.3 V), 27800, 40.5 k $\Omega$
- 15.102** (a) (250  $\mu$ A, 15.6 V), (500  $\mu$ A, 15.0 V) (b) 4300, , 165 k $\Omega$  (c)  $v_2$  (d)  $v_1$
- 15.107** (250  $\mu$ A, 4.92 V), (6.10  $\mu$ A, 4.30 V), (494  $\mu$ A, 5.00 V), 4230, , 97.5 k $\Omega$
- 15.109** (b-e) 12100, 101 k $\Omega$ , 180 k $\Omega$ , 66.3 M $\Omega$ ,  $v_2$
- 15.113** (250  $\mu$ A, 10.9 V), (2.00 mA, 9.84 V), (5.00 mA, 12.0 V), 866, , 127  $\Omega$
- 15.115** (300  $\mu$ A, 5.10 V), (500  $\mu$ A, 2.89 V), (2.00 mA, 5.00 V), 529, , 341  $\Omega$
- 15.120** (99.0  $\mu$ A, 5.00 V), (500  $\mu$ A, 3.41 V), (2.00 mA, 5.00 V), 11400, 50.5 k $\Omega$ , 224  $\Omega$
- 15.121** (4.95  $\mu$ A, 2.36 V), (24.5  $\mu$ A, 3.07 V), (245  $\mu$ A, 3.00 V), 249, 1.01 M $\Omega$ , 1.63 k $\Omega$ ,  $v_B$ ,  $v_A$ , 900,  $r_{\pi}$  and  $r_{\pi'}$  are low,  $R_{IN5}$  is low.
- 15.123** (99.0  $\mu$ A, 1.40 V), (990  $\mu$ A, 12.0 V), 189, 50.6 k $\Omega$ , 1.06 k $\Omega$
- 15.127** (24.8  $\mu$ A, 17.3 V), (24.8  $\mu$ A, 17.3 V), (9.62  $\mu$ A, 15.9 V), (490  $\mu$ A, 16.6 V), (49.0  $\mu$ A, 17.3 V), (4.95 mA, 18.0 V), 88.5 dB, 202 k $\Omega$ , 18.1  $\Omega$
- 15.129** 36.8  $\mu$ A
- 15.131** 196  $\mu$ A
- 15.135** 22.8  $\mu$ A
- 15.137** 5 mA, 0 mA, 10 mA, 12.5 percent
- 15.138** 100 percent
- 15.141** 70 mA, 19.6 V
- 15.144** 6.98 mA, 0 mA
- 15.145** 25.0 m $\Omega$
- 15.147** (a) 22.8  $\mu$ A, 43.9 M $\Omega$
- 15.151** Two of many: 75 k $\Omega$ , 62 k $\Omega$ , 150  $\Omega$ ; 68 k $\Omega$ , 12 k $\Omega$ , 1 k $\Omega$
- 15.155** 96.7  $\mu$ A, 16.3 M $\Omega$

- 15.158** 20.2  $\mu\text{A}$ , 101 M $\Omega$   
**15.164** 16.9  $\mu\text{A}$ , 168 M $\Omega$ , 5.11  $\mu\text{A}$ , 555 M $\Omega$ , 16.9  $\mu\text{A}$ , 168 M $\Omega$   
**15.166** 44.1  $\mu\text{A}$ , 22.1 M $\Omega$ , 10.0  $\mu\text{A}$ , 210 M $\Omega$   
**15.170** 100  $\mu\text{A}$ , 657 G $\Omega$   
**15.171** (9.34  $\mu\text{A}$ , 9.03 V), (4.62  $\mu\text{A}$ , 7.62 V), 96.5 dB  
**15.173**  $\omega_0 \omega_{f1} / 2$   
**15.174** 3.16 V

## Chapter 16

- 16.1** 4.06 k $\Omega$   $\parallel$  R  $\parallel$  4.31 k $\Omega$   
**16.4** 19.8 percent, 13.3 percent  
**16.6** 7.69 percent, 0.813  $\mu\text{A}$ , 0.855  $\mu\text{A}$   
**16.11** 274  $\mu\text{A}$ , 383 k $\Omega$ , 574  $\mu\text{A}$ , 192 k $\Omega$   
**16.16** (a) 944  $\mu\text{A}$ , 68.9 k $\Omega$ , 1.52 mA, 41.5 k $\Omega$   
**16.18** 458 k $\Omega$ , 103  $\mu\text{A}$ , 541 k $\Omega$ , 103  $\mu\text{A}$   
**16.20** 185  $\mu\text{A}$ , 299  $\mu\text{A}$   
**16.24** 125  $\mu\text{A}$ , 690  $\mu\text{A}$ , 1.31 mA, 600 k $\Omega$ , 100 k $\Omega$ , 66.4 k $\Omega$   
**16.27** 10  
**16.31** 15.7  $\mu\text{A}$ , 5.10 M $\Omega$   
**16.34** 12.3  $\mu\text{A}$ , 31.3 M $\Omega$ , 29.3  $\mu\text{A}$ , 15.2 M $\Omega$   
**16.38** 172 k $\Omega$ , 9.78 k $\Omega$ , 0.445  
**16.42**  $-V_{EE} + 1.16 \text{ V}$  for  $V_{CB3} \geq 0$   
**16.47**  $-V_{EE} + 1.91 = -8.09 \text{ V}$   
**16.48** 3.80/1  
**16.50** 17.5  $\mu\text{A}$ , 1.16 G $\Omega$ ; 20.3 kV; 2.11 V  
**16.52** 5%, 0  
**16.55** 16.9  $\mu\text{A}$ , 163 M $\Omega$ , 2750 V;  $2V_{BE} = 1.4 \text{ V}$   
**16.57** 3.80/1  
**16.59** 127  $\mu\text{A}$ , 1.89 M $\Omega$ , 129  $\mu\text{A}$ , 1.97 M $\Omega$   
**16.62** 8.22 k $\Omega$   
**16.65** 318  $\mu\text{A}$ , 295  $\mu\text{A}$ , 66.5  $\mu\text{A}$   
**16.68** 187  $\mu\text{A}$   
**16.72** 46.5  $\mu\text{A}$ , 140  $\mu\text{A}$   
**16.75**  $n > 1/3$   
**16.77** 26.4  $\mu\text{A}$   
**16.82** 30.7  $\mu\text{A}$ , 15.3  $\mu\text{A}$   
**16.85** 462  $\mu\text{A}$ , 308  $\mu\text{A}$

- 16.88 1.172 V, 307K  
 16.91 44.0  $\mu\text{V/K}$   
 16.94 2.293 k $\Omega$ , 10.47 k $\Omega$   
 16.96 79.1,  $6.28 \times 10^{-5}$ , 122 dB  
 16.100 1200, 0, , 2.9 V  
 16.104 (100  $\mu\text{A}$ , 8.70 V), (100  $\mu\text{A}$ , 7.45 V), (100  $\mu\text{A}$ , 2.50 V), (100  $\mu\text{A}$ , 1.25 V), 323, 152  
 16.106 (125  $\mu\text{A}$ , 1.54 V), (125  $\mu\text{A}$ , 2.79 V), (125  $\mu\text{A}$ , 2.50 V), (125  $\mu\text{A}$ , 1.25 V); 19600  
 16.109 171  $\mu\text{A}$   
 16.110 (b) 100  $\mu\text{A}$   
 16.111 (125  $\mu\text{A}$ , 8.63 V), (125  $\mu\text{A}$ , 1.31 V), (125  $\mu\text{A}$ , 10.0 V), (125  $\mu\text{A}$ , 8.71 V), (125  $\mu\text{A}$ , 1.29 V),  
 (125  $\mu\text{A}$ , 6.00 V), (125  $\mu\text{A}$ , 2.75 V); 43.4; 14,900  
 16.113 10,800  
 16.118 6400; 80,000  
 16.119 7500; 7500  
 16.122 7.78, 574  $\Omega$ ,  $3.03 \times 10^5$ , 60.0 k $\Omega$   
 16.124  $\pm 1.4$  V,  $\pm 2.4$  V  
 16.127 271 k $\Omega$ , 255  $\Omega$   
 16.129  $V_{EE} \geq 2.8$  V,  $V_{CC} \geq 1.4$  V; 3.8 V, 1.7 V  
 16.130 0.406 mS, 2.83 M $\Omega$   
 16.134 (100  $\mu\text{A}$ , 15.7 V), (50  $\mu\text{A}$ , 12.9 V), (50  $\mu\text{A}$ , 0.700 V), (50  $\mu\text{A}$ , 1.40 V), (50  $\mu\text{A}$ , 29.3 V), (100  
 $\mu\text{A}$ , 0.700 V), (100  $\mu\text{A}$ , 13.6 V), 1 mS, 752 k $\Omega$   
 16.136 (25  $\mu\text{A}$ , 2.50 V), (50  $\mu\text{A}$ , 3.20 V)  
 16.137 (a) 125  $\mu\text{A}$ , 75  $\mu\text{A}$ , 62.5  $\mu\text{A}$ , 37.5  $\mu\text{A}$  (b) 125  $\mu\text{A}$ , 0, 75  $\mu\text{A}$  (c) 125  $\mu\text{A}$ , 0, 75  $\mu\text{A}$

## Chapter 17

- 17.1  $25, \frac{s^2}{(s+1)(s+20)}$ , yes,  $\frac{25s}{(s+20)}$ , 3.18 Hz, 3.19 Hz  
 17.4  $200, \frac{1}{\frac{\square}{\square} + \frac{s \square}{10^4 \square} + \frac{s \square}{10^5 \square}}$  yes, 1.59 kHz, 1.58 kHz  
 17.7  $200, \frac{s^2}{(s+1)(s+2)}$ ,  $\frac{1}{\frac{\square}{\square} + \frac{s \square}{500 \square} + \frac{s \square}{1000 \square}}$ , .356 Hz, 71.2 Hz; 0.380 Hz, 66.7 Hz  
 17.10 (b)  $\square 14.1$  (23.0 dB), 11.8 Hz  
 17.12 19.3 dB, 151 Hz; 35.0 dB, 12.6 Hz  
 17.21 7.24 dB, 19.2 Hz  
 17.23 0.964, 0.627 Hz

- 17.24 0.152  $\mu\text{F}$
- 17.27 Cannot reach 1 Hz;  $f_L = 13.1$  Hz for  $C_1 =$  , limited by  $C_3$
- 17.29 0.351  $\mu\text{F}$
- 17.31 308 ps
- 17.34  $\approx 100$ ;  $\approx 107$
- 17.36 0.977; 0.978
- 17.37  $\approx 5100$ ,  $\approx 98.0$ ,  $\approx 5000$ ,  $\approx 100$ ;  $\approx 350$ ,  $\approx 42.9$ ,  $\approx 300$ ,  $\approx 50$
- 17.40  $\approx 98.7$ , 1.42 MHz
- 17.46  $\approx 129$ , 1.10 MHz
- 17.50  $1/10^5 RC$ ;  $1/10^6 RC$ ;  $1/sRC$
- 17.52  $(2750 \angle j4.99) \Omega$ ,  $(2730 \angle j226) \Omega$ ,  $(836 \angle j1040) \Omega$
- 17.58  $\approx 9.44$ , 43.9 Hz, 9.02 MHz; 85.1 MHz
- 17.62  $\approx 1300$ ;  $\approx 92.3$ ;  $\approx 100$ ,  $\approx 1200$
- 17.63 9.13, 40.9 MHz
- 17.66 2.30, 10.9 MHz
- 17.71 0.964, 114 MHz
- 17.73  $C_{GD} + C_{GS}/(1 + g_m R_L)$  for  $\omega \ll \omega_T$
- 17.76 99.3 kHz
- 17.77 48.2 kHz
- 17.87 4 GHz, 39.8 ps
- 17.90 781  $\mu\text{A}$
- 17.91 8.33 MHz
- 17.95 10.6 MHz, 33.3 V/ms
- 17.100 8 V/ $\mu\text{s}$
- 17.104 22.5 MHz, 2.91,  $\approx 41.1$
- 17.105 20.1 pF, 12.6,  $n = 2.81$ , 21.9 pF
- 17.107 15.2 MHz; 27.5 MHz
- 17.108 13.4 MHz, 7.98,  $112/\angle 90^\circ$ ; 4.74 MHz, 5.21,  $46.1/\angle 90^\circ$
- 17.113 10.9 MHz, 16.4,  $\approx 75.1$ ; 10.1 MHz, 3.96,  $\approx 35.4$

## Chapter 18

- 18.5  $1/(1+A\beta)$ ;  $9.99 \times 10^3$  percent
- 18.8 100 dB
- 18.13 800 M $\Omega$ ; 2.00  $\Omega$ ; 20.0 M $\Omega$ ; 50 m $\Omega$
- 18.15 18.8 k $\Omega$ , 1.02 mS,  $\approx 75.0 \times 10^3$ , 3141, 0.0993, 10.0; 0.0993 @ 0; 75,000 @ 0.0993
- 18.17 0.999, 43.9 M $\Omega$ , 2.49  $\Omega$ , 98.9 ms
- 18.20  $A\beta/(1 + A\beta)$ ; 99.9 percent
- 18.22  $\approx 33.0$  k $\Omega$ ; 8.11 k $\Omega$ ; 0.705  $\Omega$

- 18.23 82.2  $\Omega$ ; 46.2  $\Omega$ ; 32.4 k $\Omega$ ; 32.4
- 18.24 36.8  $\Omega$ ; 18.6  $\Omega$ ; 34.4 k $\Omega$
- 18.26 0.973, 973  $\Omega$
- 18.29 446 k $\Omega$ , 50.4 k $\Omega$ , 2.45 k $\Omega$
- 18.31 11.0, 15.2  $\Omega$ , 2.72 M $\Omega$
- 18.32 21.9  $\Omega$ ; 12.3  $\Omega$ ; 35.1
- 18.37  $\beta_o/(\beta_o + 1)$ ,  $2/g_m$ ,  $(\beta_o + 1)r_o$
- 18.40 58.2 dB
- 18.43 91.8
- 18.45  $(s/R_2C_2)/[s^2 + s(1/R_2C_2 + 1/(R_1||R_2)C_1) + 1/R_1R_2C_1C_2]$
- 18.50  $T_V = 987$ ,  $T_I = 110$ ,  $T = 98.5$
- 18.59 114 dB, 0 Hz, 1000 Hz, 0 Hz, 101 kHz
- 18.62 46.1 kHz, 9.31 Hz, 81.0 kHz, 5.29 Hz
- 18.69 110 kHz; A  $\approx$  2000; larger
- 18.71 yes, but almost no phase margin; 1.83°
- 18.73 90.0°
- 18.75 12°; yes
- 18.81 phase margin is undefined;  $|T(j\omega)| < 1$  for all  $\omega$
- 18.85 38.4°
- 18.86  $\omega = 1/RC$ ,  $R_F = 2R$
- 18.88 63.7 kHz, 6.85 V
- 18.90 18.4 kHz, 10.7 V
- 18.95 9.00 MHz, 1.20
- 18.101 11.2 MHz, 18.1 MHz, 1.00
- 18.102 15.9155 mH, 15.9155 fF; 10.008 MHz, 10.003 MHz
- 18.103 9.190 MHz; 9.190 MHz